DIVIDE-BY-4 PRESCALER

TEST CIRCUITS

UPB582A UPB582B UPB582C

FEATURES

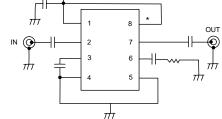
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• HIGH FREQUENCY OPERATION TO 2.8 GHz

- WIDE BAND OPERATION
- SINGLE SUPPLY VOLTAGE: Vcc = 5 V ±10%
- COMPLEMENTARY OUTPUTS

DESCRIPTION

The UPB582 series of devices are divide-by-4 silicon bipolar digital prescalers. They feature high frequency response and operate from a single 5 volt supply. The series is available in three package styles: 8 pin can (UPB582A); 8 lead ceramic flat package (UPB582B) and an 8 pin DIP (UPB582C). Applications include: frequency synthesizers, division and prescaling.



Note: All capacitors are 2200 pF, all resistors are 50 ohms. * Pin 8 is not connected for UPB582C.

ELECTRICAL CHARACTERISTICS (Vcc = $5.0 \pm 0.5 \text{ V}$, Zs = ZL = 50Ω)

PART NUMBER PACKAGE OUTLINE			UPB582A A08		UPB582B BF08		UPB582C C08				
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	TYP	MAX
Icc	Power Supply Current	mA	25	45	60	25	45	60	25	45	60
fin	Frequency Response at $PIN = -10 \text{ to } -5 \text{ dBm}^1$ $PIN = -5 \text{ to } 0 \text{ dBm}^1$ $PIN = 0 \text{ to } +5 \text{ dBm}^1$ $PIN = -2 \text{ to } +10 \text{ dBm}^2$ $PIN = +3 \text{ to } +10 \text{ dBm}^2$ $PIN = -5 \text{ to } +10 \text{ dBm}^3$ $PIN = -5 \text{ to } +10 \text{ dBm}^4$ $PIN = -3 \text{ to } +10 \text{ dBm}^5$	GHz GHz GHz GHz GHz GHz GHz GHz	0.5 0.5		2.6 2.8	0.5 0.5 0.5		2.4 2.6 2.8	0.5 0.5 0.5		2.2 2.4 2.4
Pin	Input Power at $f_{IN} = 0.5 \text{ to } 2.4 \text{ GHz}^1$ $f_{IN} = 0.5 \text{ to } 2.6 \text{ GHz}^1$ $f_{IN} = 0.5 \text{ to } 2.8 \text{ GHz}^1$ $f_{IN} = 0.5 \text{ to } 2.6 \text{ GHz}^2$ $f_{IN} = 0.5 \text{ to } 2.8 \text{ GHz}^2$ $f_{IN} = 0.5 \text{ to } 2.2 \text{ GHz}^3$ $f_{IN} = 0.5 \text{ to } 2.4 \text{ GHz}^4$ $f_{IN} = 0.5 \text{ to } 2.4 \text{ GHz}^5$	dBm dBm dBm dBm dBm dBm dBm	-2 +3		+10 +10	-10 -5 0		+5 +5 +5	-5 -5 -3		+10 +10 +10
Ρουτ	Output Power ⁶	dBm	-12	-8		-12	-8		-12	-8	
Rth (J-C)	Thermal Resistance, Junction to Case (UPB582B)	°C/W						20			

Notes:

1. TA = -40 to +85°C.

2. TA = -20 to +75°C. 5. TA = -20 to +70°C, Vcc =
$$5.0 \pm 0.25$$
 V.

3. $T_A = -35$ to $+85^{\circ}C$. 6. $T_A = +25^{\circ}C$, fin = 2.0 GHz, Pin = 0 dBm.

4. TA = -20 to +65 °C, Vcc = 5.0 ± 0.25 V.

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ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage	V	-0.5 to 6.0
Vin	Input Voltage	V	-0.5 to Vcc +0.5
PIN	Input Power	dBm	+10
PD	Total Power Dissipation UPB582B ² UPB582A UPB582C	mW mW mW	1500 750 600
Тор	Operating Temperature UPB582B UPB582A, C	°C ℃	-55 to +125 -55 to +85
Тѕтс	Storage Temperature UPB582B UPB582A UPB582C	°C ℃ ℃	-65 to +200 -55 to +200 -55 to +125

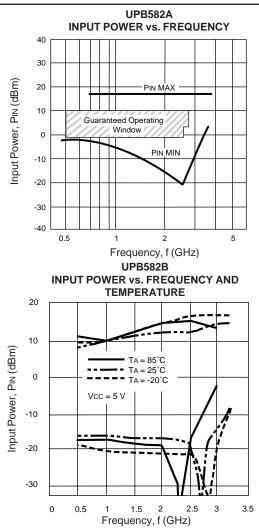
Notes

1. Operation in excess of any one of these parameters may result in permanent damage.

2. TA = Absolute Maximum Operating Temperature.

TYPICAL PERFORMANCE CURVES

(Vcc = 5 V, TA = $25^{\circ}C$)



RECOMMENDED OPERATING CONDITIONS (TA = 25°C)

SYMBOL	PARAMETER	UNITS	RATINGS
Vcc	Supply Voltage	V	4.5 to 5.5
Тор	Operating Temperature UPB582B UPB582A, C	°C ℃	-40 to +85 -20 to +75

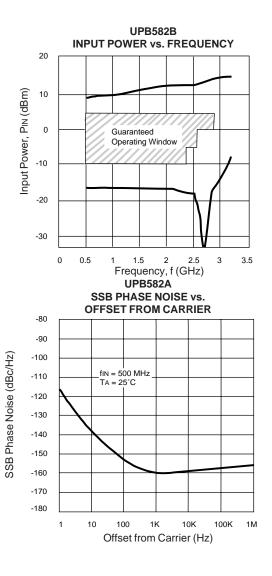
Note: Because of the high internal gain and gain compression of the UPB582, this device is prone to self-oscillation in the absence of an RF input signal. If the device will be used in an application where DC power will be applied in the absence of an RF input signal, this self-oscillation can be suppressed by any of the following means:

* Add a shunt resistor from the RF input line to ground. The blocking capacitor should be between the resistor and the UPB582, but physical separation should be minimized. Typically a resistor value between 50 and 100 ohms will suppress the self-oscillation.

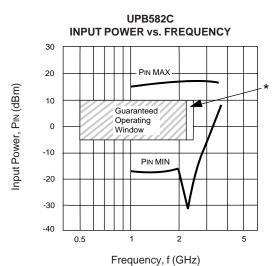
* Apply a DC offset voltage of +3.0 volts to the INPUT pin. The voltage source should be isolated from the INPUT pin by a series 1000 ohm resistor.

* Apply a DC offset voltage of +1.5 volts to the BYPASS pin. The voltage source should be isolated from the BYPASS pin by a series 1000 chm resistor.

All these approaches reduce the input sensitivity of the UPB582 (by as much as $3 \, dB$ for the example of a 50 ohm shunt resistor), but otherwise have no affect on the reliability or other electrical characteristics of this device.

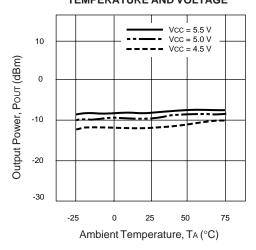


TYPICAL PERFORMANCE CURVES (TA = 25°C unless otherwise noted)



*See special conditions in Electrical Characteristics Table.

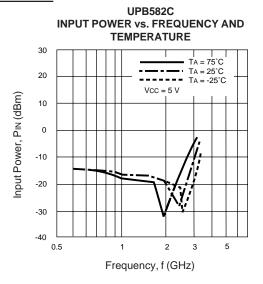
UPB582C OUTPUT POWER VS. TEMPERATURE AND VOLTAGE



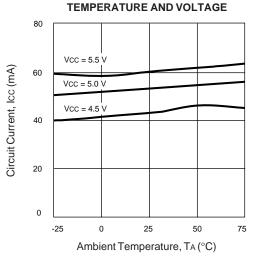
UPB582C INPUT AND OUTPUT S-PARAMETERS

Vcc = 5.0 V, Icc = 45 mA

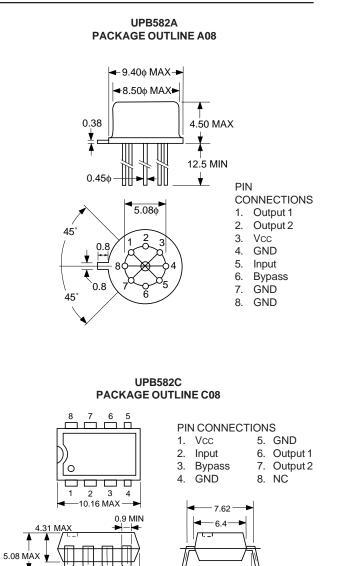
Frequency	S 11		Frequency	S 22		
(GHz)	MAG	ANG	(GHz)	MAG	ANG	
0.20	0.079	142	0.10	0.329	142	
0.40	0.246	119	0.20	0.395	104	
0.80	0.231	100	0.30	0.452	79	
1.20	0.334	91	0.40	0.482	59	
1.60	0.422	84	0.50	0.484	45	
2.00	0.553	75	0.60	0.466	36	
2.40	0.645	63	0.70	0.460	31	
2.80	0.690	49	0.80	0.474	26	
3.20	0.674	33	0.90	0.481	20	



UPB582C CIRCUIT CURRENT vs.



OUTLINE DIMENSIONS (Units in mm)



+0.10

0~15°

1.27

2.54

▶ 4 0.50

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UPB582B

PACKAGE OUTLINE BF08

▲ 2.6

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GND
Output 1

7. Output 2

8. Vcc

4.4±0.2

10.4±0.5

0.2+0.05

1.7 MAX

- 7.0±0.5 -

1.27 1.27 1.27 ±0.1 ±0.1 ±0.1

-0.4

PIN

2. Input

Bypass
GND

- 5.0±0.2 ----

CONNECTIONS 1. Vcc

6 ¦ 5

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0.51 MIN

3.2 ± 0.3 1.4 MIN→